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APPLICATION NO. 09/870530	CONT/PRIOR	CLASS 438	SUBCLASS 55	ART UNIT 2812	EXAMINER R. Poulgeon
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Chia-Hsing Chen

Method for forming nitride read only memory with indium pocket region

PTO-2040
12/99

ISSUING CLASSIFICATION									
ORIGINAL		CROSS REFERENCE(S)							
CLASS	SUBCLASS	CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)						
INTERNATIONAL CLASSIFICATION									

☐ Continued on Issue Slip inside File Jacket

 TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
<input checked="" type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.	_____ (Assistant Examiner) _____ (Date)			NOTICE OF ALLOWANCE MAILED	
<input checked="" type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent No. _____				ISSUE FEE	
	_____ (Primary Examiner) _____ (Date)			Amount Due	Date Paid
				ISSUE BATCH NUMBER	
<input checked="" type="checkbox"/> The terminal _____ months of this patent have been disclaimed.	_____ (Legal Instruments Examiner) _____ (Date)				

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